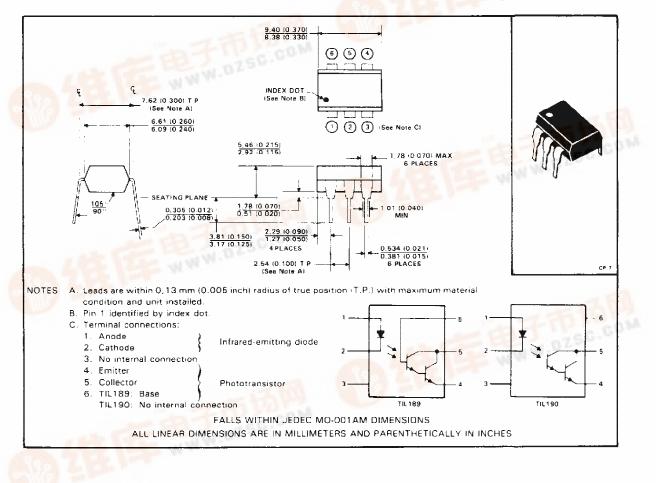


- Plastic Dual-In-Line Package
- High-Voltage Electrical Isolation, 3.535 kV Peak (2.5 kV rms)
- No Base Lead Connection on TIL190 for High-EMI Environment
- UL Recognized File #E65085

#### description

The TIL189 and TIL190 Optocouplers are designed for use in applications that require high current transfer ratio and high voltage isolation between the input and output. The TIL189 has the base connected for applications where a base signal or resistor is required. The TIL190 is designed with no internal base WWW.DZSC.COM connection for applications where high base-noise immunity is desired. Users can select from four different current gains (TIL189-1 through TIL189-4 and TIL190-1 through TIL190-4).

#### mechanical data



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## TIL189-1 THRU TIL189-4 TIL190-1 THRU TIL190-4 OPTOCOUPLERS/OPTOISOLATORS

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### absolute maximum ratings at 25 °C free-air temperature (unless otherwise noted)

Input-to-output voltage	±3.535 kV peak or dc (±2.5 kV rms
Collector-base voltage (TIL189)	
Collector-emitter voltage (see Note 1)	
Emitter-collector voltage	
Emitter-base voltage (TIL189)	
Input diode reverse voltage	
Input diode continuous forward current at (or below	N)
25 °C free-air temperature (see Note 2)	
Continuous power dissipation at (or below) 25°C f	ree-air temperature:
Infrared-emitting diode (see Note 3)	
Phototransistor (see Note 3)	
Total, infrared-emitting diode plus phototransis	tor (see Note 4)
Storage temperature range	
Lead temperature 1,6 mm (1/16-inch) from case for	

NOTES: 1. This value applies when the base-emitter diode is open circuited.

2. Derate linearly to 100°C free-air temperature at the rate of 1.33 mA/°C

3. Derate linearly to 100 °C free-air temperature at the rate of 2 mW/ °C.

4. Derate linearly to 100 °C free-air temperature at the rate of 3.33 mW/ °C.

# TIL189-1 THRU TIL189-4 TIL190-1 THRU TIL190-4 Optocouplers/optoisolators

				TIL189			TIL190			
PARAMETER		TEST CONDITIONS $I_C = 10 \mu A, I_E = 0,$ $I_F = 0$	MIN TYP		MAX	MIN	TYP	MAX	UNIT	
Collector-base V(BR)CBO breakdown voltage			100	•••					v	
Collector-emitter V(BR)CEO breakdown voltage		lc = 1 mA, lg = 0, lp = 0	55	<u> </u>		55			v	
Emitter-base V(BR)EBO breakdown voltage		ltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0,$ $I_{F} = 0$	14						v
Emitter-collector VIBRIECO breakdown voltage		$I_{\rm E} = 100 \ \mu {\rm A}, \ I_{\rm F} = 0$				7			v	
R	Input diode st reverse curren		VA = 3 V			10			10	μΑ
I <sub>C(on)</sub> colle	Photo- -state transistor lector operation			5			5			]
			10			10			mA	
			20 30			20 30				
		V <sub>CE</sub> = 1 V, I <sub>F</sub> = 10 mA, I <sub>B</sub> = 0	50			50		<u></u>		
	Photodiode operation		$V_{CB} = 1 V$ , $l_F = 10 mA$ , $l_E = 0$	5	15					μA
IC(off)	Off-state collector curre	int	$V_{CE} = 10 V, I_{E} = 0,$ $I_{B} = 0$	-	1	100		1	100	nA
Transistor static hFE forward current transfer ratio		V <sub>CE</sub> = 1 V, I <sub>C</sub> ≈ 10 mA, I <sub>F</sub> = 0		25000						
۷F	Input diode st forward voltag		I <sub>F</sub> = 10 mA		1.2	1.5		1.2	1.5	v
VCE(sat)	Collector-emit saturation volt		$I_{\rm C} = 50  {\rm mA},  {\rm i}_{\rm F} = 10  {\rm mA},  {\rm i}_{\rm B} = 0$		0.87	1		0.87	1	v
an	Input-to-outpu internal resista		V <sub>in-out</sub> = ±500 V, See Note 5	1011			1011			Ω
Cio	Input-to-outpu capacitance	t	Vin-out = 0, f = 1 mHz, See Note 5		1	1.3		1	1.3	pF

## electrical characteristics at 25 °C free-air temperature (unless otherwise noted)

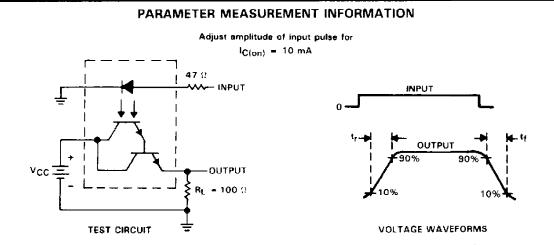
NOTE 5: These parameters are measured between both input-diode leads shorted together and all the phototransistor leads shorted together.

## switching characteristics at 25 °C free-air temperature

PARAMETER	TEST CONDITIONS		TIL189						
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
t, Rise time	V <sub>CC</sub> = 10 V.	I <sub>C(on)</sub> = 10 mA.		100			100		μS
tf Fall time	$R_{L} = 100 \Omega_{c}$	see Figure 1		100			100		μs



## TIL189-1 THRU TIL189-4 TIL190-1 THRU TIL190-4 Optocouplers/optoisolators



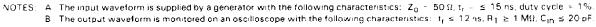
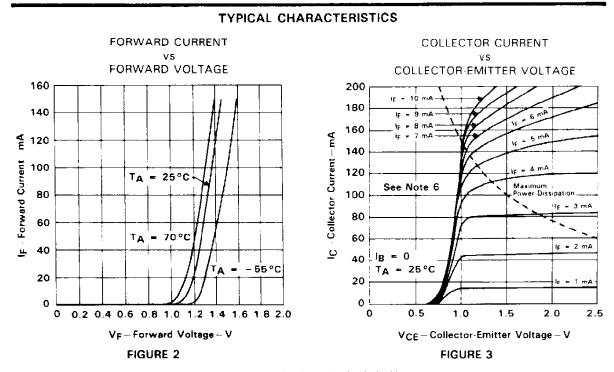
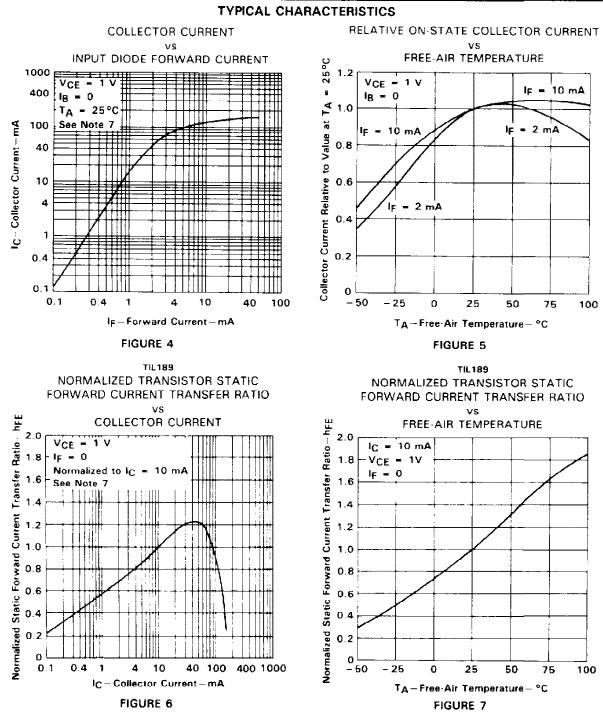


FIGURE 1. SWITCHING TIMES



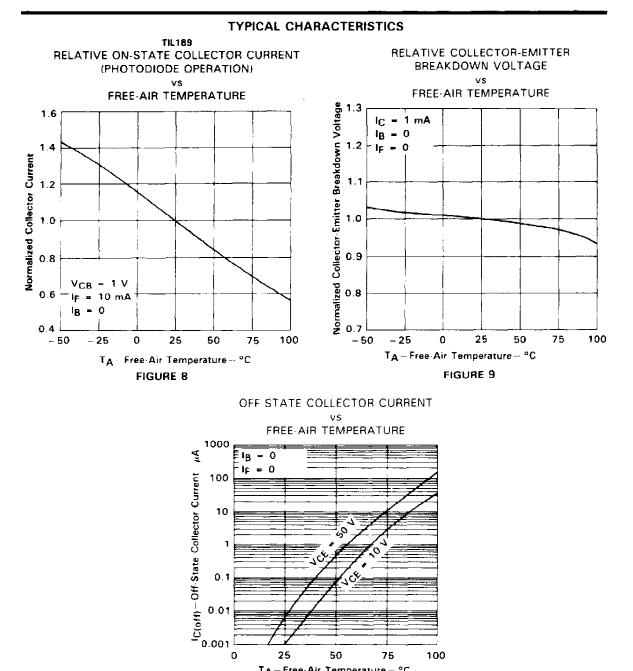
NOTE 6 Pulse operation is required for operation beyond limits shown by the dashed line.





NOTE 7: These parameters were measured using pulse techniques  $t_{W} = 1$  ms, duty cycle  $\leq 2\%$  .

# **TIL189-1 THRU TIL189-4** TIL190-1 THRU TIL190-4 **OPTOCOUPLERS/OPTOISOLATORS**



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50

TA-Free-Air Temperature- °C **FIGURE 10** 

75

100

0

25

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